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## REVISION HISTORY

### 7/2016—Rev. D to Rev. E

|                                        |            |
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| Changed CP-8-2 to CP-8-13 .....        | Throughout |
| Changes to Figure 1 and Figure 2 ..... | 1          |
| Added Patent Note, Note 1 .....        | 1          |
| Updated Outline Dimensions .....       | 13         |
| Changes to Ordering Guide .....        | 15         |

### 7/2006—Rev. C to Rev. D

|                                              |           |
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| Added AD8664 .....                           | Universal |
| Added 14-Lead SOIC_N and 14-Lead TSSOP ..... | Universal |
| Changes to Features.....                     | 1         |
| Changes to Table 1 .....                     | 3         |
| Changes to Table 2 .....                     | 4         |
| Changes to Table 3 .....                     | 5         |
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### 5/2006—Rev. B to Rev. C

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### 3/2006—Rev. A to Rev. B

|                                  |           |
|----------------------------------|-----------|
| Added AD8662 .....               | Universal |
| Added MSOP .....                 | Universal |
| Changes to Table 1 .....         | 3         |
| Changes to Table 2 .....         | 4         |
| Changes to Table 3 .....         | 5         |
| Changes to Table 4 .....         | 6         |
| Changes to Table 5 .....         | 7         |
| Updated Outline Dimensions ..... | 13        |
| Changes to Ordering Guide .....  | 13        |

### 1/2006—Rev. 0 to Rev. A

|                                 |           |
|---------------------------------|-----------|
| Added LFCSP_VD .....            | Universal |
| Changes to Table 1 .....        | 3         |
| Changes to Table 2 .....        | 4         |
| Changes to Ordering Guide ..... | 13        |

### 9/2005—Revision 0: Initial Version

## SPECIFICATIONS

## AD8661/AD8662/AD8664 ELECTRICAL CHARACTERISTICS—SOIC, MSOP, AND TSSOP

$V_S = 5.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

| Parameter                    | Symbol           | Test Conditions/Comments                                        | Min  | Typ      | Max  | Unit                         |
|------------------------------|------------------|-----------------------------------------------------------------|------|----------|------|------------------------------|
| INPUT CHARACTERISTICS        |                  |                                                                 |      |          |      |                              |
| Offset Voltage               | $V_{OS}$         | $V_{CM} = V_S/2$                                                |      | 30       | 100  | $\mu\text{V}$                |
| AD8661                       |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                   |      |          | 1000 | $\mu\text{V}$                |
| AD8661                       |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 1400 | $\mu\text{V}$                |
| AD8662                       |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 1000 | $\mu\text{V}$                |
| AD8664                       |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 1200 | $\mu\text{V}$                |
| Input Bias Current           | $I_B$            |                                                                 |      | 0.3      | 1    | $\text{pA}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                   |      |          | 50   | $\text{pA}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 300  | $\text{pA}$                  |
| Input Offset Current         | $I_{OS}$         |                                                                 |      | 0.2      | 0.5  | $\text{pA}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                   |      |          | 20   | $\text{pA}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 75   | $\text{pA}$                  |
| Input Voltage Range          |                  |                                                                 | -0.1 |          | +3.0 | $\text{V}$                   |
| Common-Mode Rejection Ratio  | CMRR             | $V_{CM} = -0.1\text{ V to }+3.0\text{ V}$                       | 85   | 100      |      | $\text{dB}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  | 80   | 100      |      | $\text{dB}$                  |
| Large Signal Voltage Gain    | $A_{VO}$         | $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }4.5\text{ V}$ | 100  | 220      |      | $\text{V/mV}$                |
| Offset Voltage Drift         | $TCV_{OS}$       |                                                                 |      |          |      |                              |
| AD8661                       |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      | 3        | 10   | $\mu\text{V}/^\circ\text{C}$ |
| AD8662, AD8664               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      | 2        | 9    | $\mu\text{V}/^\circ\text{C}$ |
| OUTPUT CHARACTERISTICS       |                  |                                                                 |      |          |      |                              |
| Output Voltage High          | $V_{OH}$         | $I_L = 1\text{ mA}$                                             | 4.85 | 4.93     |      | $\text{V}$                   |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  | 4.80 |          |      | $\text{V}$                   |
| Output Voltage Low           | $V_{OL}$         | $I_L = 1\text{ mA}$                                             |      | 50       | 100  | $\text{mV}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 110  | $\text{mV}$                  |
| Short-Circuit Current        | $I_{SC}$         |                                                                 |      | $\pm 19$ |      | $\text{mA}$                  |
| Closed-Loop Output Impedance | $Z_{OUT}$        | $f = 1\text{ MHz}$ , $A_V = 1$                                  |      | 50       |      | $\Omega$                     |
| POWER SUPPLY                 |                  |                                                                 |      |          |      |                              |
| Supply Current per Amplifier | $I_{SY}$         | $V_O = V_S/2$                                                   |      | 1.15     | 1.40 | $\text{mA}$                  |
|                              |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                  |      |          | 2.0  | $\text{mA}$                  |
| DYNAMIC PERFORMANCE          |                  |                                                                 |      |          |      |                              |
| Slew Rate                    | SR               | $R_L = 2\text{ k}\Omega$                                        |      | 3.5      |      | $\text{V}/\mu\text{s}$       |
| Gain Bandwidth Product       | GBP              |                                                                 |      | 4        |      | $\text{MHz}$                 |
| Phase Margin                 | $\Phi_O$         |                                                                 |      | 65       |      | Degrees                      |
| NOISE PERFORMANCE            |                  |                                                                 |      |          |      |                              |
| Peak-to-Peak Noise           | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to }10\text{ Hz}$                             |      | 2.5      |      | $\mu\text{V p-p}$            |
| Voltage Noise Density        | $e_n$            | $f = 1\text{ kHz}$                                              |      | 12       |      | $\text{nV}/\sqrt{\text{Hz}}$ |
|                              |                  | $f = 10\text{ kHz}$                                             |      | 10       |      | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density        | $i_n$            | $f = 1\text{ kHz}$                                              |      | 0.1      |      | $\text{pA}/\sqrt{\text{Hz}}$ |

**AD8661/AD8662/AD8664 ELECTRICAL CHARACTERISTICS—SOIC, MSOP, AND TSSOP**

$V_S = 16.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 2.**

| Parameter                     | Symbol           | Test Conditions/Comments                                          | Min   | Typ       | Max   | Unit                         |
|-------------------------------|------------------|-------------------------------------------------------------------|-------|-----------|-------|------------------------------|
| <b>INPUT CHARACTERISTICS</b>  |                  |                                                                   |       |           |       |                              |
| Offset Voltage                | $V_{OS}$         | $V_{CM} = V_S/2$                                                  |       | 50        | 160   | $\mu\text{V}$                |
| AD8661                        |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                     |       |           | 1000  | $\mu\text{V}$                |
| AD8661                        |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 1400  | $\mu\text{V}$                |
| AD8662                        |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 1000  | $\mu\text{V}$                |
| AD8664                        |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 1200  | $\mu\text{V}$                |
| Input Bias Current            | $I_B$            |                                                                   |       | 0.3       | 1     | $\text{pA}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                     |       |           | 50    | $\text{pA}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 300   | $\text{pA}$                  |
| Input Offset Current          | $I_{OS}$         |                                                                   |       | 0.2       | 0.5   | $\text{pA}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                     |       |           | 20    | $\text{pA}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 75    | $\text{pA}$                  |
| Input Voltage Range           |                  |                                                                   | -0.1  |           | +14.0 | $\text{V}$                   |
| Common-Mode Rejection Ratio   | CMRR             | $V_{CM} = -0.1\text{ V to } +14.0\text{ V}$                       | 90    | 110       |       | $\text{dB}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    | 90    | 110       |       | $\text{dB}$                  |
| Large Signal Voltage Gain     | $A_{VO}$         | $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to } 15.5\text{ V}$ | 200   | 360       |       | $\text{V/mV}$                |
| Offset Voltage Drift          | $TCV_{OS}$       |                                                                   |       |           |       |                              |
| AD8661                        |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       | 3         | 10    | $\mu\text{V}/^\circ\text{C}$ |
| AD8662, AD8664                |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       | 2         | 9     | $\mu\text{V}/^\circ\text{C}$ |
| <b>OUTPUT CHARACTERISTICS</b> |                  |                                                                   |       |           |       |                              |
| Output Voltage High           | $V_{OH}$         | $I_L = 1\text{ mA}$                                               | 15.93 | 15.97     |       | $\text{V}$                   |
|                               |                  | $I_L = 10\text{ mA}$                                              | 15.60 | 15.70     |       | $\text{V}$                   |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    | 15.50 |           |       | $\text{V}$                   |
| Output Voltage Low            | $V_{OL}$         | $I_L = 1\text{ mA}$                                               |       | 24        | 50    | $\text{mV}$                  |
|                               |                  | $I_L = 10\text{ mA}$                                              |       | 190       | 300   | $\text{mV}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 350   | $\text{mV}$                  |
| Short-Circuit Current         | $I_{SC}$         |                                                                   |       | $\pm 140$ |       | $\text{mA}$                  |
| Closed-Loop Output Impedance  | $Z_{OUT}$        | $f = 1\text{ MHz}$ , $A_V = 1$                                    |       | 45        |       | $\Omega$                     |
| <b>POWER SUPPLY</b>           |                  |                                                                   |       |           |       |                              |
| Power Supply Rejection Ratio  | PSRR             | $V_S = 5\text{ V to } 16\text{ V}$                                | 95    | 110       |       | $\text{dB}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    | 95    | 115       |       | $\text{dB}$                  |
| Supply Current per Amplifier  | $I_{SY}$         | $V_O = V_S/2$                                                     |       | 1.25      | 1.55  | $\text{mA}$                  |
|                               |                  | $-40^\circ\text{C} < T_A < +125^\circ\text{C}$                    |       |           | 2.1   | $\text{mA}$                  |
| <b>DYNAMIC PERFORMANCE</b>    |                  |                                                                   |       |           |       |                              |
| Slew Rate                     | SR               | $R_L = 2\text{ k}\Omega$                                          |       | 3.5       |       | $\text{V}/\mu\text{s}$       |
| Gain Bandwidth Product        | GBP              |                                                                   |       | 4         |       | $\text{MHz}$                 |
| Phase Margin                  | $\Phi_O$         |                                                                   |       | 65        |       | Degrees                      |
| <b>NOISE PERFORMANCE</b>      |                  |                                                                   |       |           |       |                              |
| Peak-to-Peak Noise            | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to } 10\text{ Hz}$                              |       | 2.5       |       | $\mu\text{V p-p}$            |
| Voltage Noise Density         | $e_n$            | $f = 1\text{ kHz}$                                                |       | 12        |       | $\text{nV}/\sqrt{\text{Hz}}$ |
|                               |                  | $f = 10\text{ kHz}$                                               |       | 10        |       | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density         | $i_n$            | $f = 1\text{ kHz}$                                                |       | 0.1       |       | $\text{pA}/\sqrt{\text{Hz}}$ |

**AD8661 ELECTRICAL CHARACTERISTICS—LFCSP ONLY**

$V_S = 5.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 3.

| Parameter                     | Symbol           | Test Conditions/Comments                                                                    | Min  | Typ      | Max  | Unit                         |
|-------------------------------|------------------|---------------------------------------------------------------------------------------------|------|----------|------|------------------------------|
| <b>INPUT CHARACTERISTICS</b>  |                  |                                                                                             |      |          |      |                              |
| Offset Voltage                | $V_{OS}$         | $V_{CM} = V_S/2$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                           |      | 50       | 300  | $\mu\text{V}$                |
| Input Bias Current            | $I_B$            | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                               |      | 0.3      | 1    | $\mu\text{A}$                |
| Input Offset Current          | $I_{OS}$         | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                               |      | 0.2      | 0.5  | $\mu\text{A}$                |
| Input Voltage Range           |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                               | -0.1 |          | 20   | $\mu\text{A}$                |
| Common-Mode Rejection Ratio   | CMRR             | $V_{CM} = -0.1\text{ V to } +3.0\text{ V}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ | 85   | 100      | +3.0 | $\text{dB}$                  |
| Large Signal Voltage Gain     | $A_{VO}$         | $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to } 4.5\text{ V}$                            | 80   | 100      |      | $\text{dB}$                  |
| Offset Voltage Drift          | $TCV_{OS}$       | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                               | 100  | 240      |      | $\text{V/mV}$                |
| <b>OUTPUT CHARACTERISTICS</b> |                  |                                                                                             |      |          |      |                              |
| Output Voltage High           | $V_{OH}$         | $I_L = 1\text{ mA}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                        | 4.85 | 4.93     |      | $\text{V}$                   |
| Output Voltage Low            | $V_{OL}$         | $I_L = 1\text{ mA}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                        | 4.80 | 50       | 100  | $\text{mV}$                  |
| Short-Circuit Current         | $I_{SC}$         |                                                                                             |      | $\pm 19$ | 120  | $\text{mA}$                  |
| Closed-Loop Output Impedance  | $Z_{OUT}$        | $f = 1\text{ MHz}$ , $A_V = 1$                                                              |      | 65       |      | $\Omega$                     |
| <b>POWER SUPPLY</b>           |                  |                                                                                             |      |          |      |                              |
| Supply Current per Amplifier  | $I_{SY}$         | $V_O = V_S/2$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                              |      | 1.15     | 1.40 | $\text{mA}$                  |
| <b>DYNAMIC PERFORMANCE</b>    |                  |                                                                                             |      |          |      |                              |
| Slew Rate                     | SR               | $R_L = 2\text{ k}\Omega$                                                                    |      | 3.5      |      | $\text{V}/\mu\text{s}$       |
| Gain Bandwidth Product        | GBP              |                                                                                             |      | 4        |      | $\text{MHz}$                 |
| Phase Margin                  | $\Phi_O$         |                                                                                             |      | 65       |      | Degrees                      |
| <b>NOISE PERFORMANCE</b>      |                  |                                                                                             |      |          |      |                              |
| Peak-to-Peak Noise            | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to } 10\text{ Hz}$                                                        |      | 2.5      |      | $\mu\text{V p-p}$            |
| Voltage Noise Density         | $e_n$            | $f = 1\text{ kHz}$                                                                          |      | 12       |      | $\text{nV}/\sqrt{\text{Hz}}$ |
|                               |                  | $f = 10\text{ kHz}$                                                                         |      | 10       |      | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density         | $i_n$            | $f = 1\text{ kHz}$                                                                          |      | 0.1      |      | $\text{pA}/\sqrt{\text{Hz}}$ |

**AD8661 ELECTRICAL CHARACTERISTICS—LFCSP ONLY**

$V_S = 16.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 4.**

| Parameter                     | Symbol           | Test Conditions/Comments                                                                     | Min                     | Typ            | Max         | Unit                         |
|-------------------------------|------------------|----------------------------------------------------------------------------------------------|-------------------------|----------------|-------------|------------------------------|
| <b>INPUT CHARACTERISTICS</b>  |                  |                                                                                              |                         |                |             |                              |
| Offset Voltage                | $V_{OS}$         | $V_{CM} = V_S/2$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                            |                         | 50             | 300         | $\mu\text{V}$                |
| Input Bias Current            | $I_B$            | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                                |                         | 0.3            | 2000        | $\mu\text{V}$                |
| Input Offset Current          | $I_{OS}$         | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                                |                         | 0.2            | 50          | $\text{pA}$                  |
| Input Voltage Range           |                  | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                                | -0.1                    |                | 20          | $\text{pA}$                  |
| Common-Mode Rejection Ratio   | CMRR             | $V_{CM} = -0.1\text{ V to }+14.0\text{ V}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$  | 90                      | 110            | +14.0       | $\text{dB}$                  |
| Large Signal Voltage Gain     | $A_{VO}$         | $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }15.5\text{ V}$                             | 90                      | 110            |             | $\text{dB}$                  |
| Offset Voltage Drift          | $TCV_{OS}$       | $-40^\circ\text{C} < T_A < +85^\circ\text{C}$                                                | 200                     | 420            |             | $\text{V/mV}$                |
|                               |                  |                                                                                              |                         | 4              | 17          | $\mu\text{V}/^\circ\text{C}$ |
| <b>OUTPUT CHARACTERISTICS</b> |                  |                                                                                              |                         |                |             |                              |
| Output Voltage High           | $V_{OH}$         | $I_L = 1\text{ mA}$<br>$I_L = 10\text{ mA}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ | 15.95<br>15.60<br>15.50 | 15.97<br>15.70 |             | $\text{V}$                   |
| Output Voltage Low            | $V_{OL}$         | $I_L = 1\text{ mA}$<br>$I_L = 10\text{ mA}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$ |                         | 24<br>210      | 50<br>350   | $\text{mV}$                  |
| Short-Circuit Current         | $I_{SC}$         |                                                                                              |                         | $\pm 140$      | 400         | $\text{mV}$                  |
| Closed-Loop Output Impedance  | $Z_{OUT}$        | $f = 1\text{ MHz}$ , $A_V = 1$                                                               |                         | 45             |             | $\text{mA}$                  |
| <b>POWER SUPPLY</b>           |                  |                                                                                              |                         |                |             |                              |
| Power Supply Rejection Ratio  | PSRR             | $V_S = 5\text{ V to }16\text{ V}$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$           | 95<br>95                | 110<br>115     |             | $\text{dB}$                  |
| Supply Current per Amplifier  | $I_{SY}$         | $V_O = V_S/2$<br>$-40^\circ\text{C} < T_A < +85^\circ\text{C}$                               |                         | 1.25           | 1.55<br>1.9 | $\text{mA}$                  |
| <b>DYNAMIC PERFORMANCE</b>    |                  |                                                                                              |                         |                |             |                              |
| Slew Rate                     | SR               | $R_L = 2\text{ k}\Omega$                                                                     |                         | 3.5            |             | $\text{V}/\mu\text{s}$       |
| Gain Bandwidth Product        | GBP              |                                                                                              |                         | 4              |             | $\text{MHz}$                 |
| Phase Margin                  | $\Phi_O$         |                                                                                              |                         | 65             |             | Degrees                      |
| <b>NOISE PERFORMANCE</b>      |                  |                                                                                              |                         |                |             |                              |
| Peak-to-Peak Noise            | $e_n\text{ p-p}$ | $f = 0.1\text{ Hz to }10\text{ Hz}$                                                          |                         | 2.5            |             | $\mu\text{V p-p}$            |
| Voltage Noise Density         | $e_n$            | $f = 1\text{ kHz}$<br>$f = 10\text{ kHz}$                                                    |                         | 12<br>10       |             | $\text{nV}/\sqrt{\text{Hz}}$ |
| Current Noise Density         | $i_n$            | $f = 1\text{ kHz}$                                                                           |                         | 0.1            |             | $\text{pA}/\sqrt{\text{Hz}}$ |

## ABSOLUTE MAXIMUM RATINGS

Table 5.

| Parameter                            | Rating          |
|--------------------------------------|-----------------|
| Supply Voltage                       | 18 V            |
| Input Voltage                        | −0.1 V to $V_S$ |
| Differential Input Voltage           | 18 V            |
| Output Short-Circuit Duration to GND | Indefinite      |
| Storage Temperature Range            | −60°C to +150°C |
| Operating Temperature Range          |                 |
| R-8, RM-8, R-14, and RU-14           | −40°C to +125°C |
| CP-8-13                              | −40°C to +85°C  |
| Junction Temperature Range           | −65°C to +150°C |
| Lead Temperature, Soldering (60 sec) | 300°C           |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 6. Thermal Resistance

| Package Type  | $\theta_{JA}$   | $\theta_{JC}$   | Unit |
|---------------|-----------------|-----------------|------|
| 8-Lead SOIC   | 121             | 43              | °C/W |
| 8-Lead LFCSP  | 75 <sup>1</sup> | 18 <sup>1</sup> | °C/W |
| 8-Lead MSOP   | 142             | 44              | °C/W |
| 14-Lead SOIC  | 88.2            | 56.3            | °C/W |
| 14-Lead TSSOP | 114             | 23.3            | °C/W |

<sup>1</sup> Exposed pad soldered to application board.

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

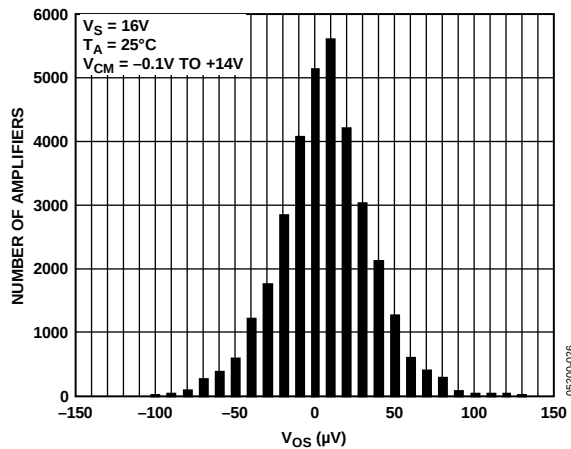


Figure 7. Input Offset Voltage Distribution

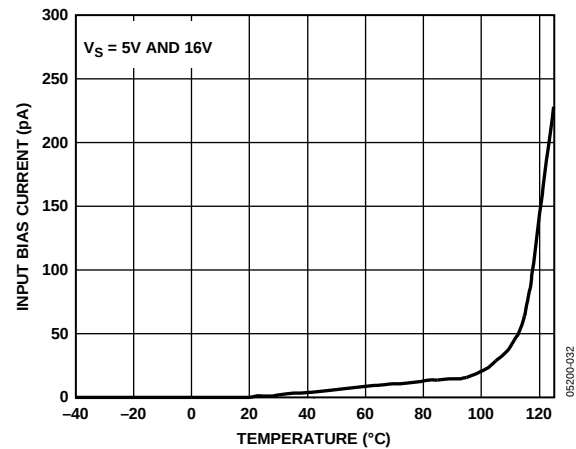


Figure 10. Input Bias Current vs. Temperature

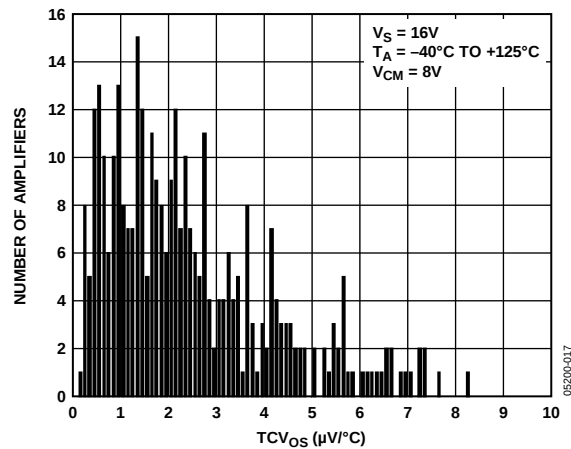


Figure 8. Offset Voltage Drift Distribution

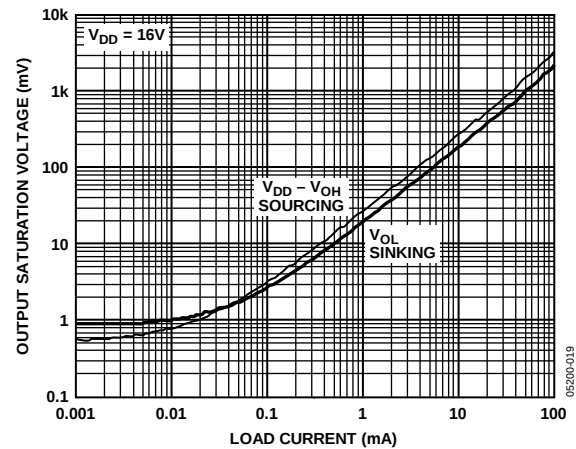


Figure 11. Output Swing Saturation Voltage vs. Load Current

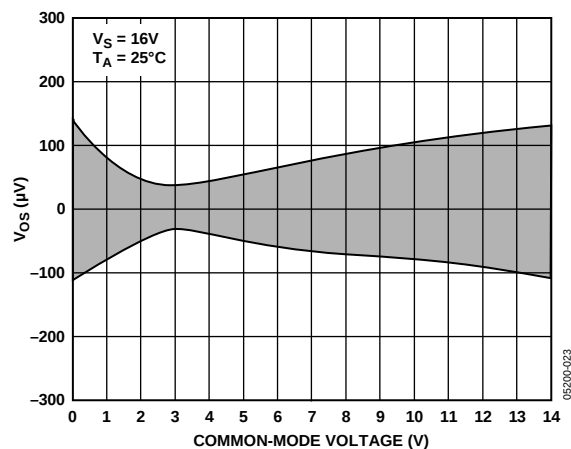
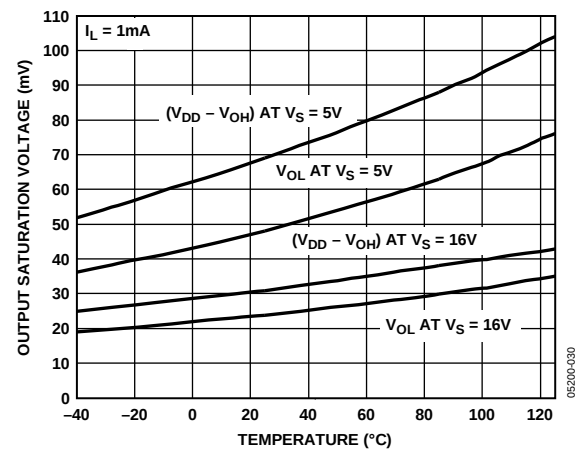


Figure 9. Input Offset Voltage vs. Common-Mode Voltage

Figure 12. Output Swing Saturation Voltage vs. Temperature,  $I_L = 1\text{ mA}$

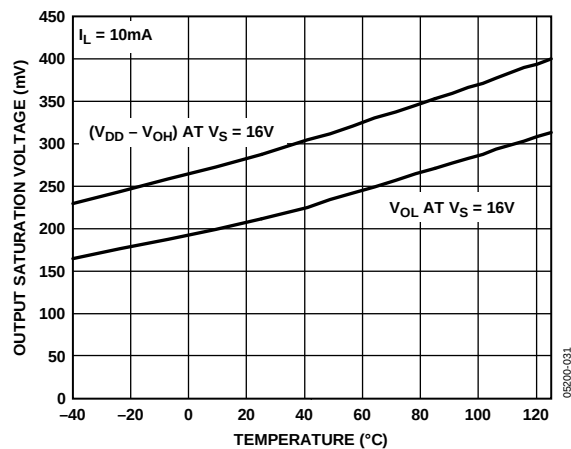
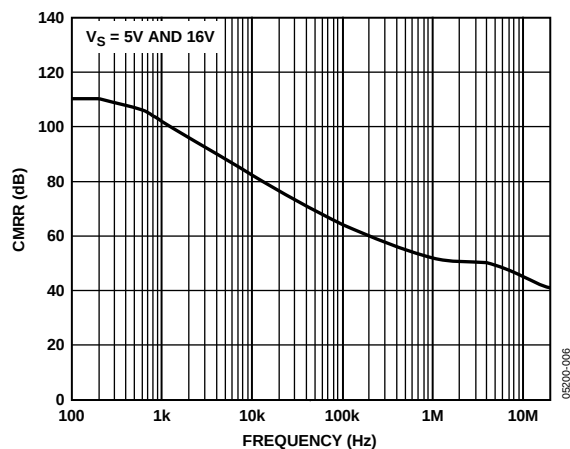
Figure 13. Output Swing Saturation Voltage vs. Temperature,  $I_L = 10\text{mA}$ 

Figure 16. CMRR vs. Frequency

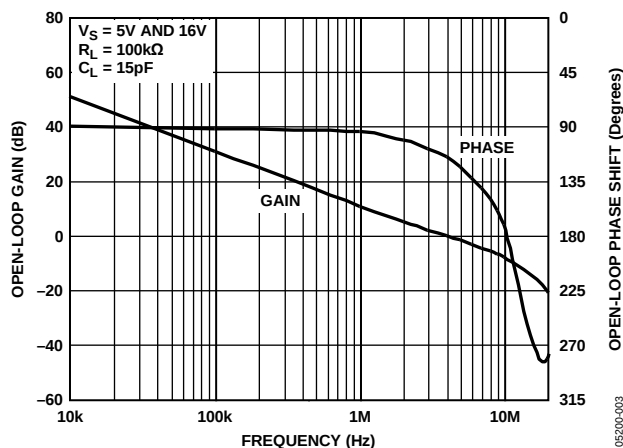


Figure 14. Open-Loop Gain and Phase Shift vs. Frequency

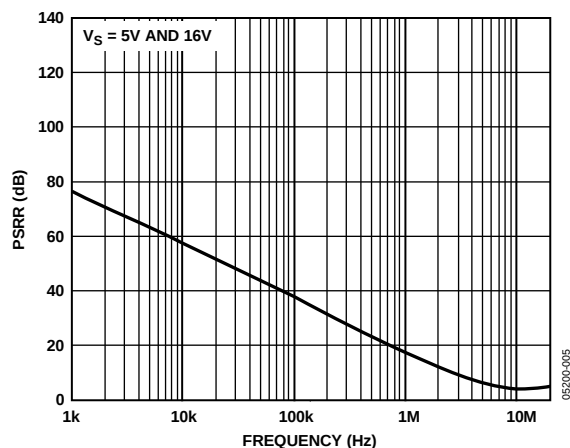


Figure 17. PSRR vs. Frequency

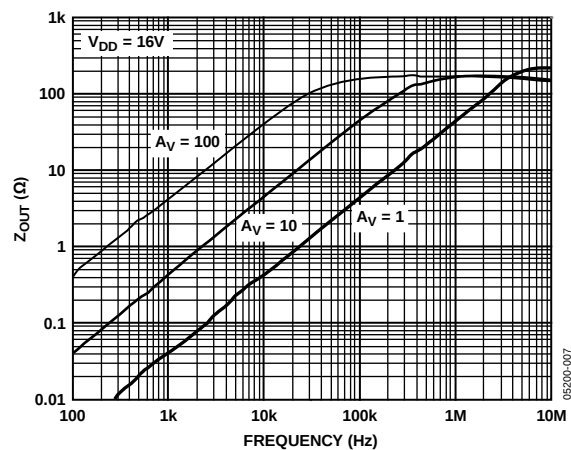


Figure 15. Closed-Loop Output Impedance vs. Frequency

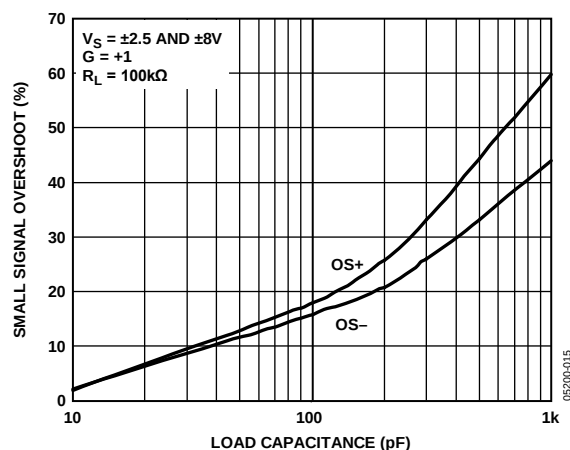


Figure 18. Small Signal Overshoot vs. Load Capacitance

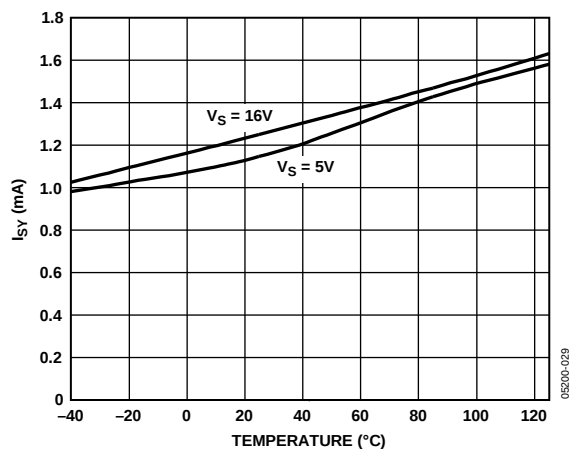


Figure 19. Supply Current vs. Temperature

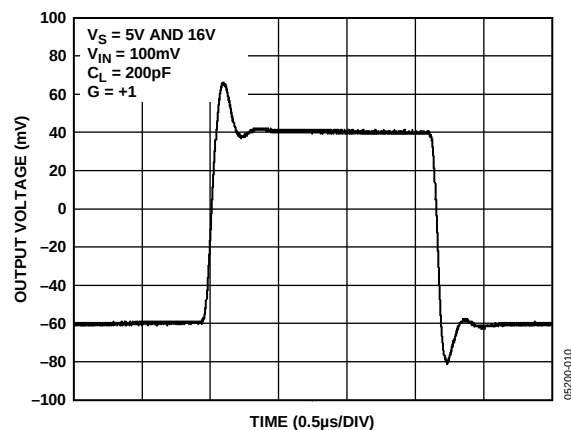


Figure 22. Small Signal Transient Response

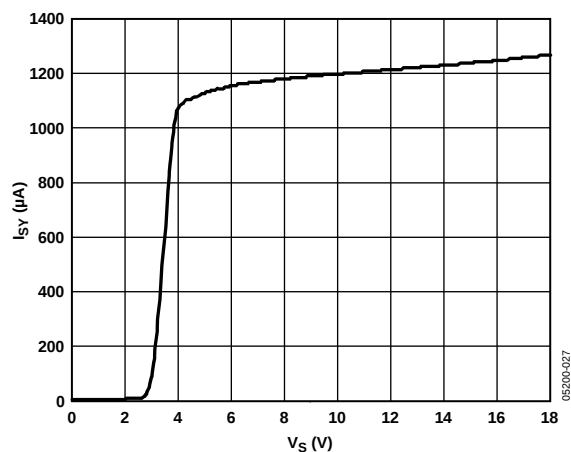
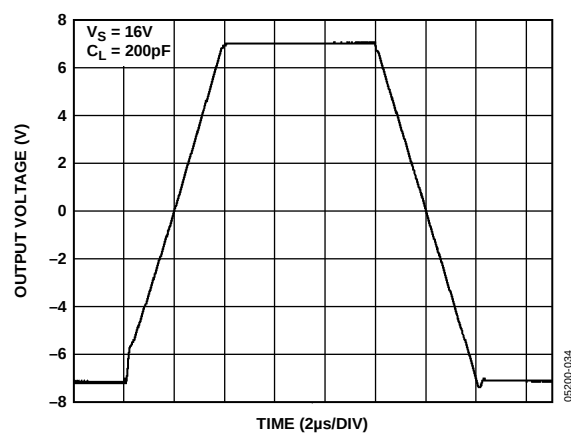
Figure 20. Supply Current vs. Supply Voltage  
(Dual-Supply Configuration),  $T_A = 25^\circ C$ 

Figure 23. Large Signal Transient Response

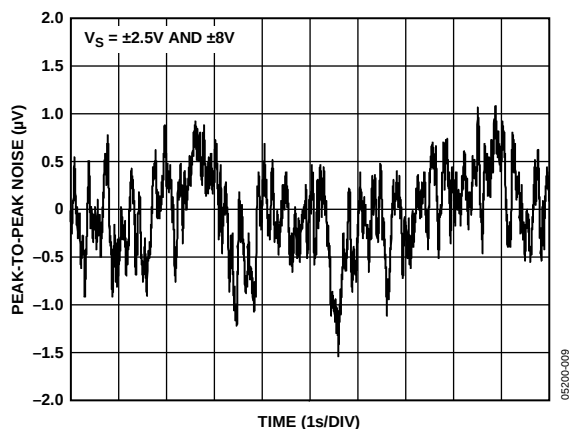


Figure 21. 0.1 Hz to 10 Hz Input Voltage Noise

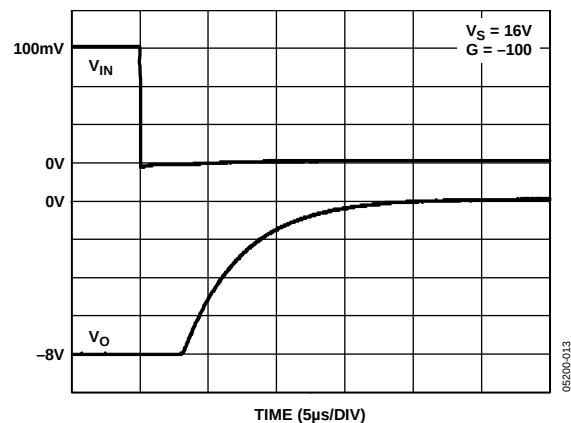


Figure 24. Positive Overload Recovery

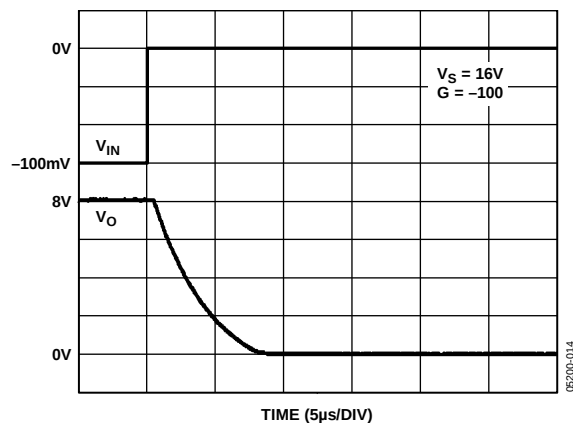


Figure 25. Negative Overload Recovery

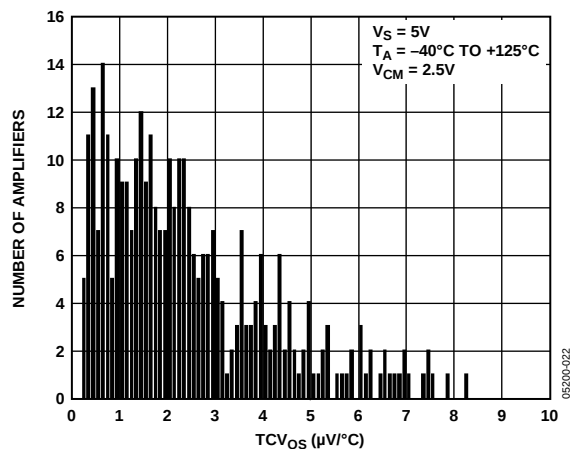


Figure 28. Offset Voltage Drift Distribution

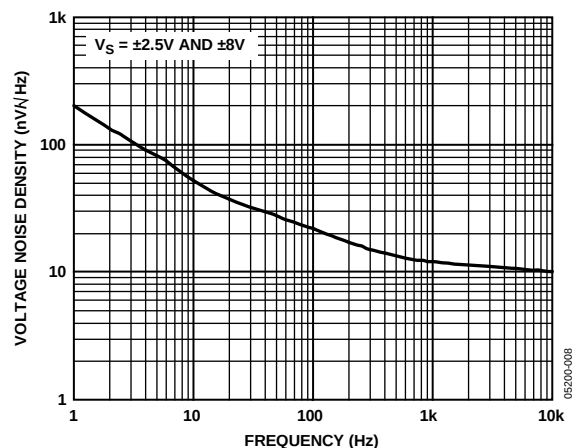


Figure 26. Voltage Noise Density vs. Frequency

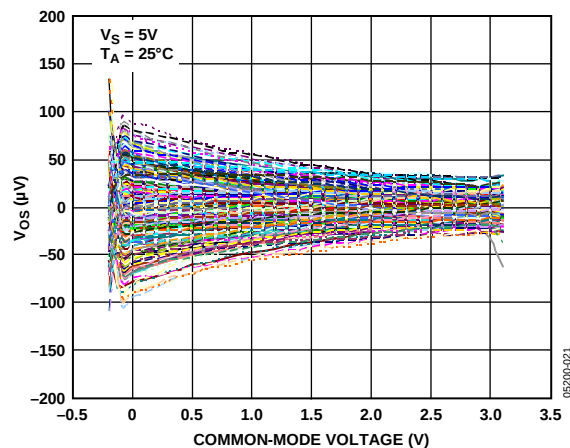


Figure 29. Input Offset Voltage vs. Common-Mode Voltage

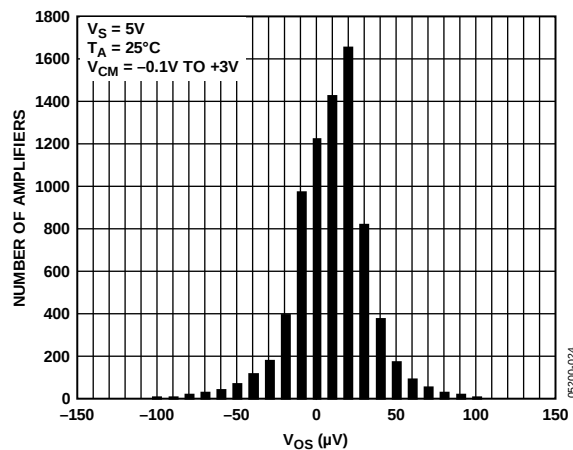


Figure 27. Input Offset Voltage Distribution

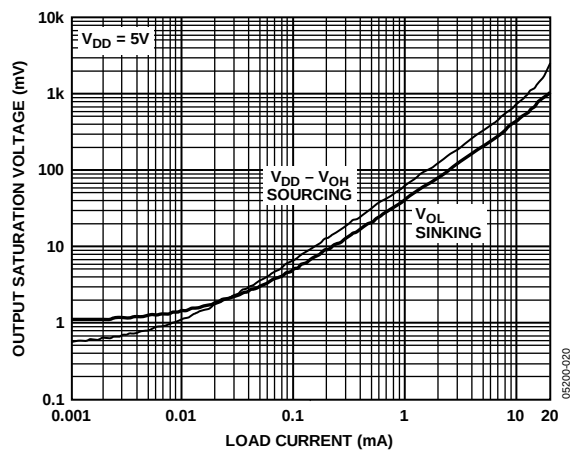


Figure 30. Output Swing Saturation Voltage vs. Load Current

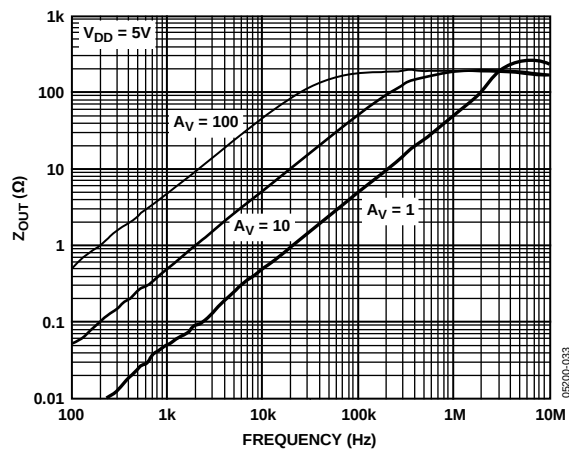


Figure 31. Closed-Loop Output Impedance vs. Frequency

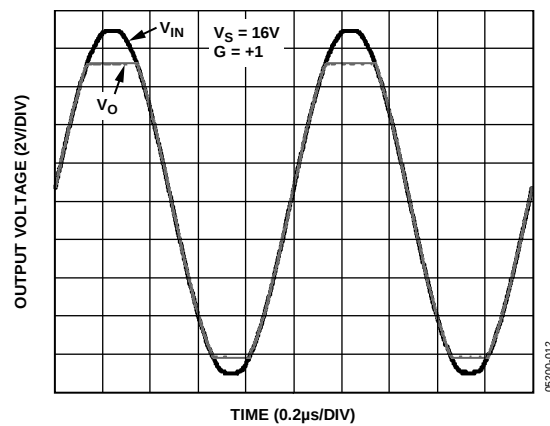


Figure 33. No Phase Reversal

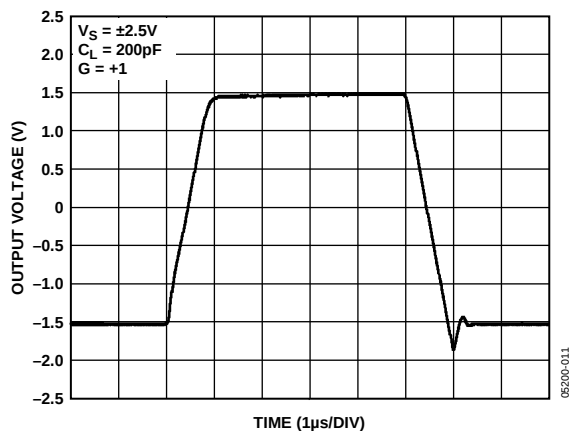
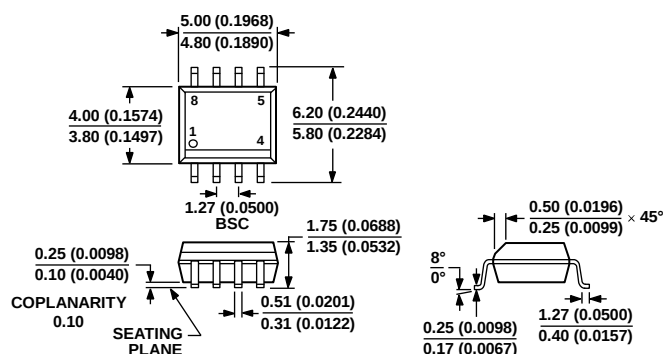


Figure 32. Large Signal Transient Response

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-A A  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

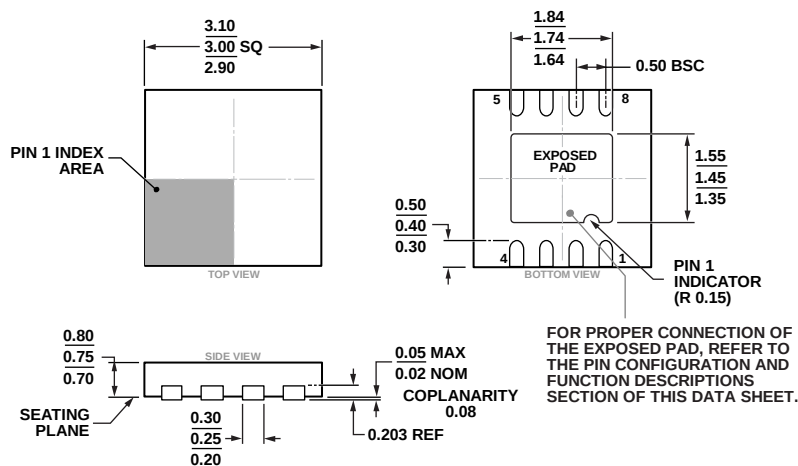
060506-A

Figure 34. 8-Lead Small Outline Package [SOIC\_N]

Narrow Body

(R-8)

Dimensions shown in millimeters and (inches)



FOR PROPER CONNECTION OF  
THE EXPOSED PAD, REFER TO  
THE PIN CONFIGURATION AND  
FUNCTION DESCRIPTIONS  
SECTION OF THIS DATA SHEET.

COMPLIANT TO JEDEC STANDARDS MO-229-WEED-4

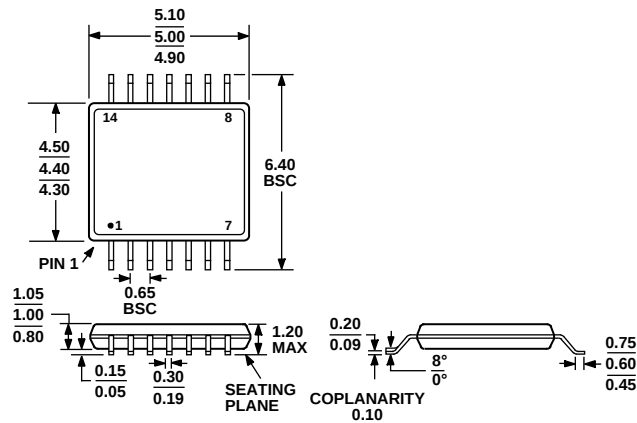
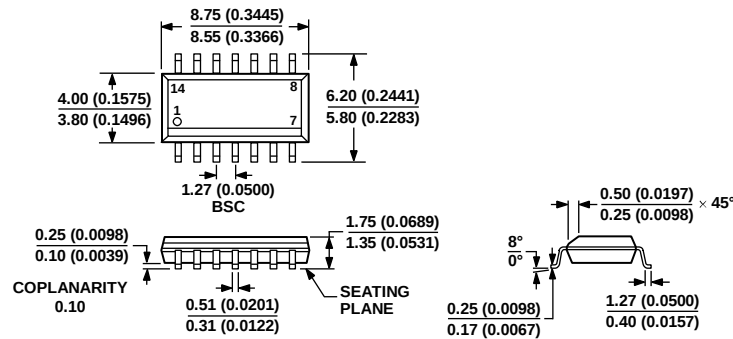
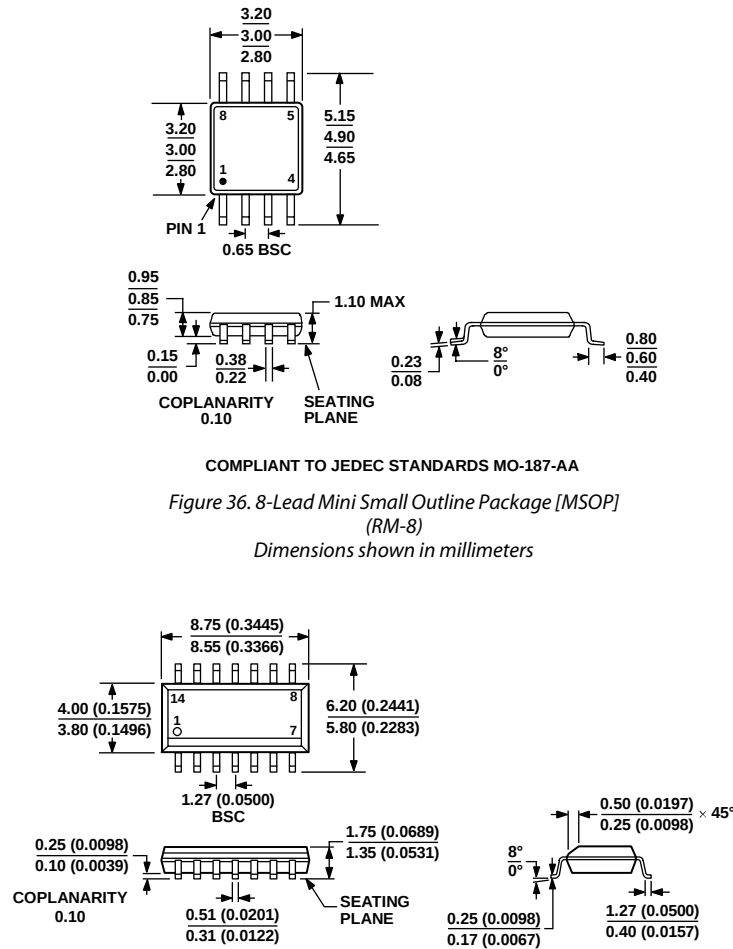
Figure 35. 8-Lead Lead Frame Chip Scale Package [LFCSP]

3 mm × 3 mm Body and 0.75 mm Package Height

(CP-8-13)

Dimensions shown in millimeters

05-11-2016-A



## ORDERING GUIDE

| Model <sup>1</sup> | Temperature Range | Package Description                               | Package Option | Branding |
|--------------------|-------------------|---------------------------------------------------|----------------|----------|
| AD8661ARZ          | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            | A0M      |
| AD8661ARZ-REEL     | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            |          |
| AD8661ARZ-REEL7    | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            |          |
| AD8661ACPZ-R2      | –40°C to +85°C    | 8-Lead Lead Frame Chip Scale Package [LFCSP]      | CP-8-13        |          |
| AD8661ACPZ-REEL7   | –40°C to +85°C    | 8-Lead Lead Frame Chip Scale Package [LFCSP]      | CP-8-13        |          |
| AD8662ARZ          | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            | A10      |
| AD8662ARZ-REEL     | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            |          |
| AD8662ARZ-REEL7    | –40°C to +125°C   | 8-Lead Small Outline Package [SOIC_N]             | R-8            |          |
| AD8662ARMZ         | –40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]          | RM-8           |          |
| AD8662ARMZ-REEL    | –40°C to +125°C   | 8-Lead Mini Small Outline Package [MSOP]          | RM-8           |          |
| AD8664ARZ          | –40°C to +125°C   | 14-Lead Standard Small Outline Package [SOIC_N]   | R-14           |          |
| AD8664ARZ-REEL     | –40°C to +125°C   | 14-Lead Standard Small Outline Package [SOIC_N]   | R-14           |          |
| AD8664ARZ-REEL7    | –40°C to +125°C   | 14-Lead Standard Small Outline Package [SOIC_N]   | R-14           |          |
| AD8664ARUZ         | –40°C to +125°C   | 14-Lead Thin Shrink Small Outline Package [TSSOP] | RU-14          |          |
| AD8664ARUZ-REEL    | –40°C to +125°C   | 14-Lead Thin Shrink Small Outline Package [TSSOP] | RU-14          |          |

<sup>1</sup> Z = RoHS Compliant Part.

## NOTES